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product

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semiconductors :: product :: [Bridge Rectifiers \(In Line\)](#)

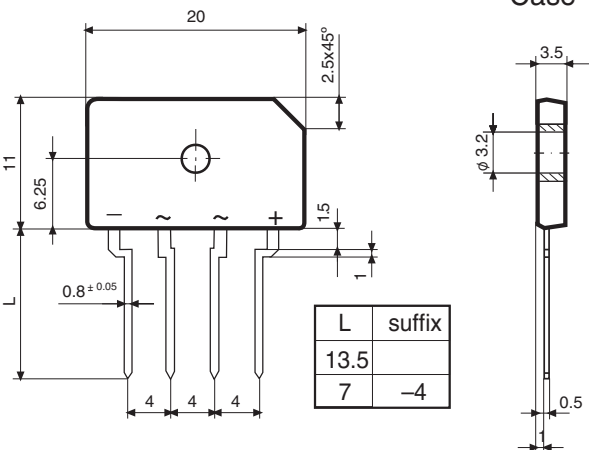
Product: Bridge Rectifiers (In Line)

Bridge Rectifiers are key devices in many applications where a rectifier signal is required as Input voltage. Linear Power Supplies, SMPS, Battery Chargers, Electronic Ballast... are some applications where they are used.

Manufactured using HYPERRECTIFIER® technology, we offer these devices in several different packages: SMD, Dual In Line, Round, In Line and Square Power.

Product	Family	$I_{F(AV)}$ (A)	I_{FSM} (A)	V_{RRM} (V)	V_f (V)	OUTLINE
FBI1.5M4S1	FBI1.5-4S1	1.5	50	1000	1.0	In Line small

1.5 Amp. Glass Passivated Bridge Rectifier

<p>Dimensions in mm.</p>  <p>• Mounting Instructions</p> <ul style="list-style-type: none"> • High temperature soldering guaranteed: 260 °C – 10 sc. • Recommended mounting torque: 8 Kg.cm. 	<p>Plastic Case</p> <p>Voltage 50 to 1000 V.</p> <p>Current 1.5 A.</p> <p>HYPERECTIFIER®</p> <ul style="list-style-type: none"> • Glass Passivated Junction Chips. • UL recognized under component index file number E320541. • Lead and polarity identifications. • Case: Molded Plastic. • Ideal for printed circuit board (P.C.B.). • The plastic material carries U/L recognition 94 V-O.
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Maximum Ratings, according to IEC publication No. 134

		FBI1.5A 4S1	FBI1.5B 4S1	FBI1.5D 4S1	FBI1.5G 4S1	FBI1.5J 4S1	FBI1.5K 4S1	FBI1.5M 4S1
V_{RRM}	Peak recurrent reverse voltage (V)	50	100	200	400	600	800	1000
V_{RMS}	Maximum RMS voltage (V)	35	70	140	280	420	560	700
$I_{F(AV)}$	Max. Average forward current with heatsink without heatsink	4.0 A at 65 °C 1.5 A at 25 °C						
I_{FSM}	8.3 ms. peak forward surge current (Jedec Method)	50 A						
I^2t	Rating for fusing (t<8.3 ms.)	10 A ² sec						
V_{DIS}	Dielectric strength (terminals to case, AC 1 min.)	1500 V						
T_j	Operating temperature range	– 55 to + 150 °C						
T_{stg}	Storage temperature range	– 55 to +150 °C						

Electrical Characteristics at Tamb = 25°C

V_F	Max. forward voltage drop per element at $I_F = 1$ A	1.0 V
I_R	Max. reverse current per element at V_{RRM}	5 μ A
$R_{th(j-c)}$	MAXIMUM THERMAL RESISTANCE Junction-Case. With Heatsink.	12 °C/W
$R_{th(j-a)}$	Junction-Ambient. Without Heatsink.	45 °C/W